



### 1 Mbit/s High Speed Transistor Coupler

#### Features

- High speed: 1 Mbit/s
- High isolation voltage between input and output (Viso=3750 Vrms )
- Guaranteed performance from 0°C to 70°C
- Wide operating temperature range of -55°C to 125°C
- Green Package
- Regulatory Approvals
  - UL - UL1577 (E364000)
  - VDE - EN60747-5-5(VDE0884-5)
  - CQC – GB4943.1, GB8898
  - IEC60065, IEC60950

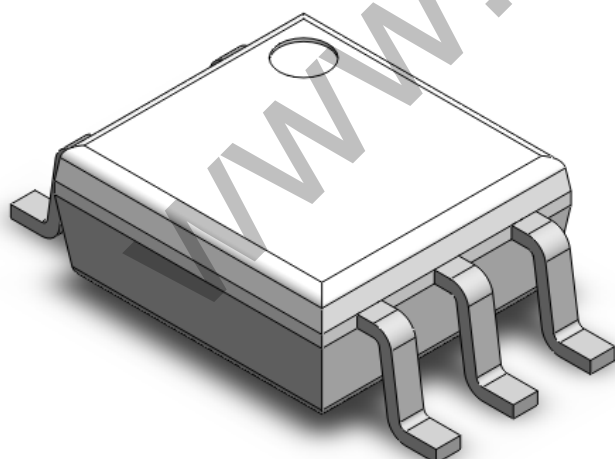
#### Description

The CTM452 and CTM453 devices each consist of an infrared emitting diode, optically coupled to a high speed photo detector transistor. A separate connection for the photodiode bias and output-transistor collector increase the speed by several orders of magnitude over conventional phototransistor couplers by reducing the base-collector capacitance of the input transistor. The devices are packaged in a Mini-Flat package.

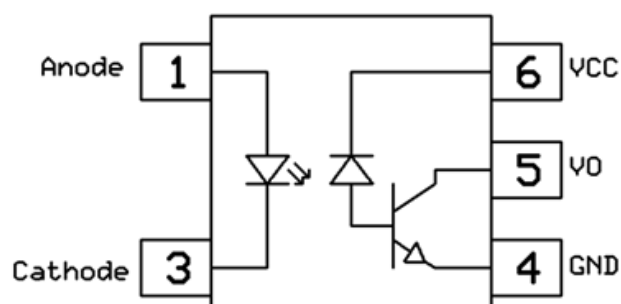
#### Applications

- Line receivers
- Telecommunication equipment
- Feedback loop in switch-mode power supplies
- Home appliances
- High speed logic ground isolation

#### Package Outline



#### Schematic





CTM452, CTM453

5 Pin Mini-Flat

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**Absolute Maximum Rating at 25°C**

Symbol	Parameters	Ratings	Units	Notes
V <sub>ISO</sub>	Isolation voltage *1	3750	V <sub>RMS</sub>	
T <sub>OPR</sub>	Operating temperature	-55 ~ +125	°C	
T <sub>STG</sub>	Storage temperature	-55 ~ +150	°C	
T <sub>SOL</sub>	Soldering temperature *2	260	°C	
<b>Emitter</b>				
I <sub>F</sub>	Forward current	25	mA	
I <sub>FP</sub>	Peak forward current (50% duty, 1ms P.W)	50	mA	
I <sub>F(TRANS)</sub>	Peak transient current (≤1μs P.W,300pps)	1	A	
V <sub>R</sub>	Reverse voltage	5	V	
P <sub>D</sub>	Power dissipation	45	mW	
<b>Detector</b>				
P <sub>D</sub>	Power dissipation	100	mW	
I <sub>O(AVG)</sub>	Average Output current	8	mA	
I <sub>O(Peak)</sub>	Peak Output current	16	mA	
V <sub>O</sub>	Output voltage	-0.5 to 20	V	
V <sub>CC</sub>	Supply voltage	-0.5 to 30	V	



## Electrical Characteristics

$T_A = 0 - 70^\circ\text{C}$  (unless otherwise specified). Typical values are measured at  $T_A = 25^\circ\text{C}$  and  $V_{CC}=5\text{V}$

### Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$V_F$	Forward voltage	$I_F = 16\text{mA}$	-	1.6	1.8	V	
$V_R$	Reverse Voltage	$I_R = 10\mu\text{A}$	5.0	-	-	V	
$\Delta V_F/\Delta T_A$	Temperature coefficient of forward voltage	$I_F = 16\text{mA}$	-	-1.6	-	mV/ $^\circ\text{C}$	

### Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$I_{OH}$	Logic High Output Current	$I_F=0\text{mA}, V_O=V_{CC}=5.5\text{V}, T_A=25^\circ\text{C}$	-	0.001	0.5	$\mu\text{A}$	
		$I_F=0\text{mA}, V_O=V_{CC}=3.3\text{V}, T_A=25^\circ\text{C}$		0.001	0.4		
		$I_F=0\text{mA}, V_O=V_{CC}=15\text{V}, T_A=25^\circ\text{C}$	-	0.01	1		
		$I_F=0\text{mA}, V_O=V_{CC}=15\text{V}$	-	-	50		
$I_{CCL}$	Logic Low Supply Current	$I_F=16\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}$	-	120	200	$\mu\text{A}$	
$I_{CCH}$	Logic High Supply Current	$I_F=0\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}, T_A=25^\circ\text{C}$	-	0.01	1	$\mu\text{A}$	
		$I_F=0\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}$	-	-	2		



### Electrical Characteristics

$T_A = 0 - 70^\circ\text{C}$  (unless otherwise specified). Typical values are measured at  $T_A = 25^\circ\text{C}$  and  $V_{CC} = 5\text{V}$

#### Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	$I_F = 16\text{mA}$ , $V_O = 0.4\text{V}$ , $V_{CC} = 4.5\text{V}$ , $T_A = 25^\circ\text{C}$	20	-	50	%	
		$I_F = 16\text{mA}$ , $V_O = 0.5\text{V}$ , $V_{CC} = 4.5\text{V}$	15	-	-		
		$I_F = 16\text{mA}$ , $V_O = 0.4\text{V}$ , $V_{CC} = 3.3\text{V}$ , $T_A = 25^\circ\text{C}$	18	-	51		
		$I_F = 16\text{mA}$ , $V_O = 0.5\text{V}$ , $V_{CC} = 3.3\text{V}$	13	-	-		
VOL	Logic Low Output Voltage	$I_F = 16\text{mA}$ , $I_O = 3\text{mA}$ , $V_{CC} = 4.5\text{V}$ , $T_A = 25^\circ\text{C}$	-	-	0.4	V	
		$I_F = 16\text{mA}$ , $I_O = 3\text{mA}$ , $V_{CC} = 3.3\text{V}$ , $T_A = 25^\circ\text{C}$	-	-	0.4		
		$I_F = 16\text{mA}$ , $I_O = 2.4\text{mA}$ , $V_{CC} = 4.5\text{V}$	-	-	0.5		
		$I_F = 16\text{mA}$ , $I_O = 2.4\text{mA}$ , $V_{CC} = 3.3\text{V}$	-	-	0.5		

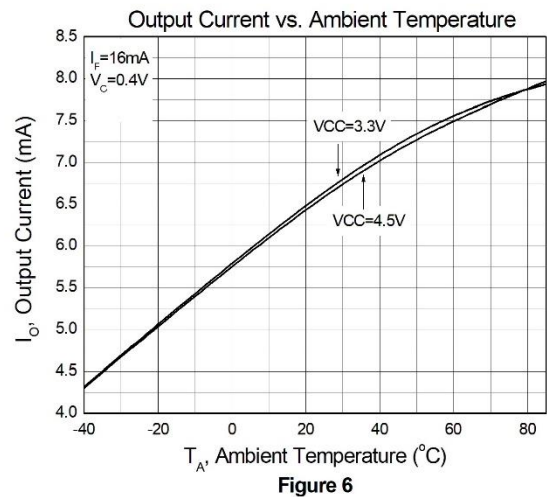
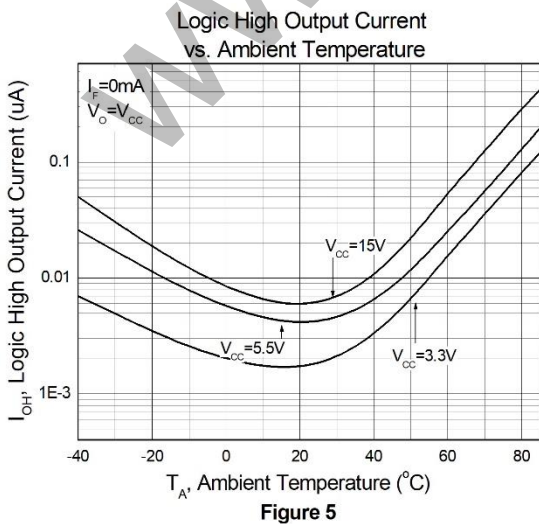
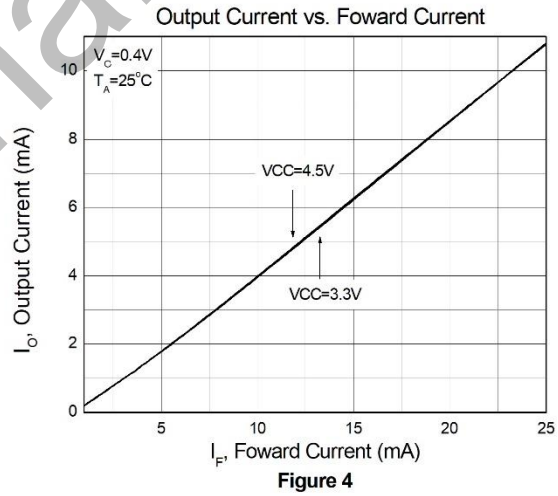
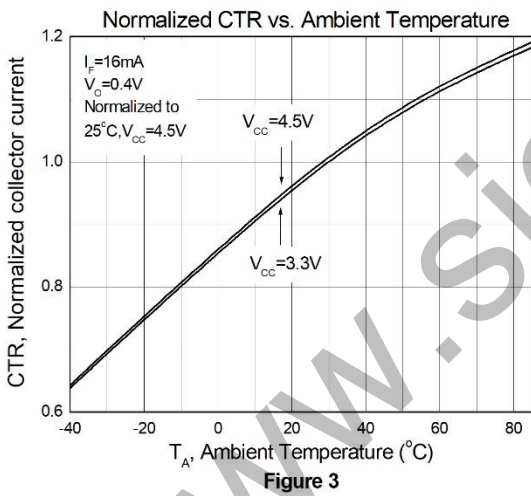
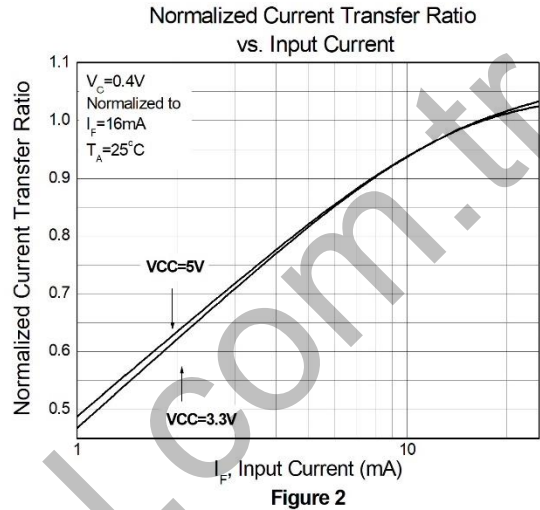
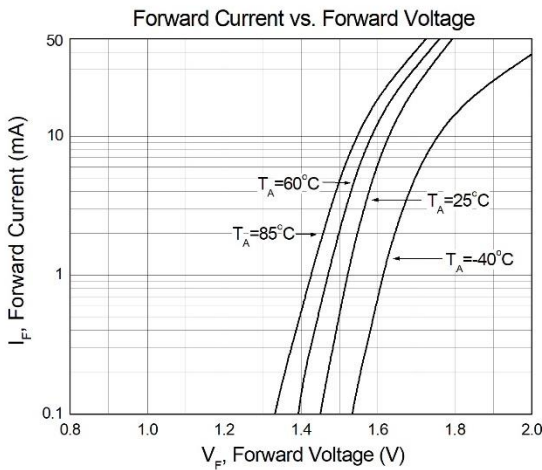


**Switching Characteristics**

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
T <sub>PHL</sub>	Propagation Delay Time Logic High to Logic Low	I <sub>F</sub> =16mA, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C	-	0.35	0.8	μs	
		I <sub>F</sub> =16mA, R <sub>L</sub> =1.9KΩ	-	-	1.0		
		I <sub>F</sub> =16mA, V <sub>CC</sub> =3.3V, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C		0.4	1		
		I <sub>F</sub> =16mA, V <sub>CC</sub> =3.3V, R <sub>L</sub> =1.9KΩ			1.4		
T <sub>PLH</sub>	Propagation Delay Time Logic Low to Logic High	I <sub>F</sub> =16mA, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C	-	0.3	0.8	μs	
		I <sub>F</sub> =16mA, R <sub>L</sub> =1.9KΩ	-	-	1.0		
		I <sub>F</sub> =16mA, V <sub>CC</sub> =3.3V, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C			1.5		
		I <sub>F</sub> =16mA, V <sub>CC</sub> =3.3V, R <sub>L</sub> =1.9KΩ			2.0		
CM <sub>H</sub>	Common Mode Transient Immunity at Logic High	CTM452 I <sub>F</sub> = 0mA , V <sub>CM</sub> =10Vp-p, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C	5,000	-	-	V/μs	
		CTM453 I <sub>F</sub> = 0mA , V <sub>CM</sub> =1500Vp-p, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C	15,000	-	-		
CM <sub>L</sub>	Common Mode Transient Immunity at Logic Low	CTM452 I <sub>F</sub> = 16mA , V <sub>CM</sub> =10Vp-p, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C	5,000	-	-	V/μs	
		CTM453 I <sub>F</sub> = 16mA , V <sub>CM</sub> =1500Vp-p, R <sub>L</sub> =1.9KΩ, T <sub>A</sub> =25°C	15,000	-	-		



Typical Characteristic Curves





Typical Characteristic Curves

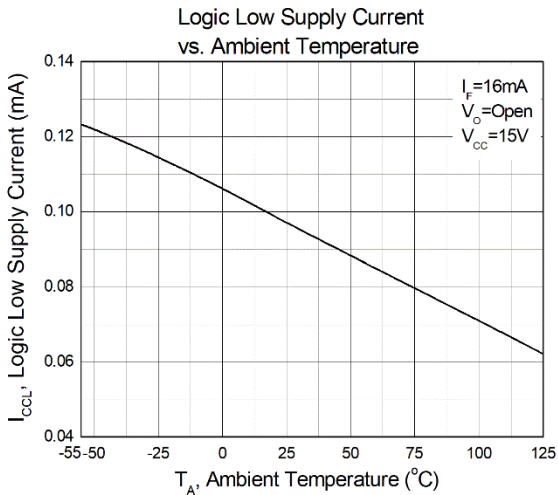


Figure 7

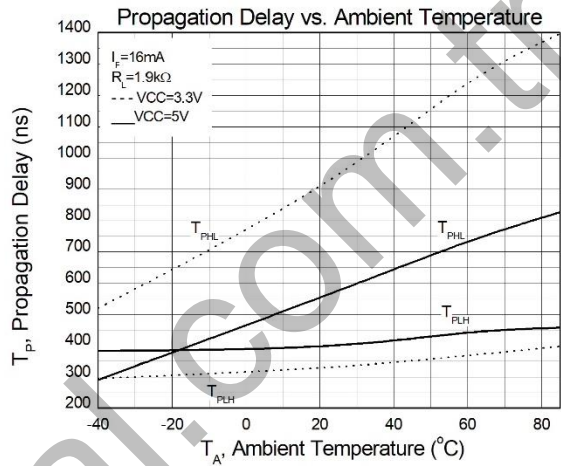


Figure 8

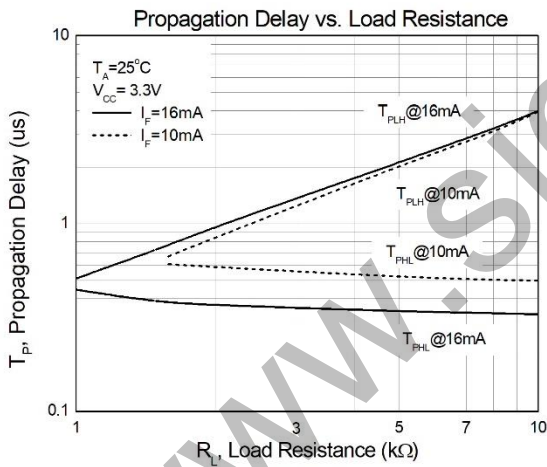


Figure 9

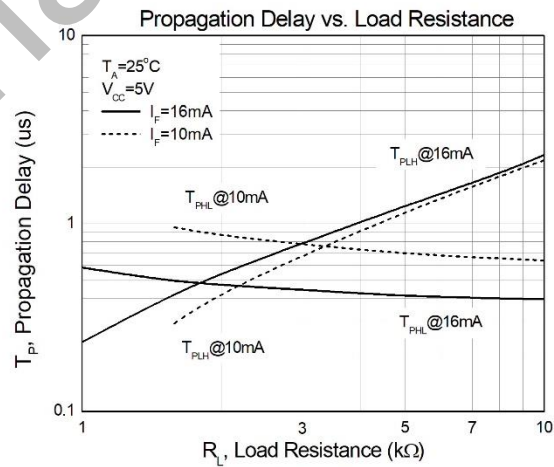
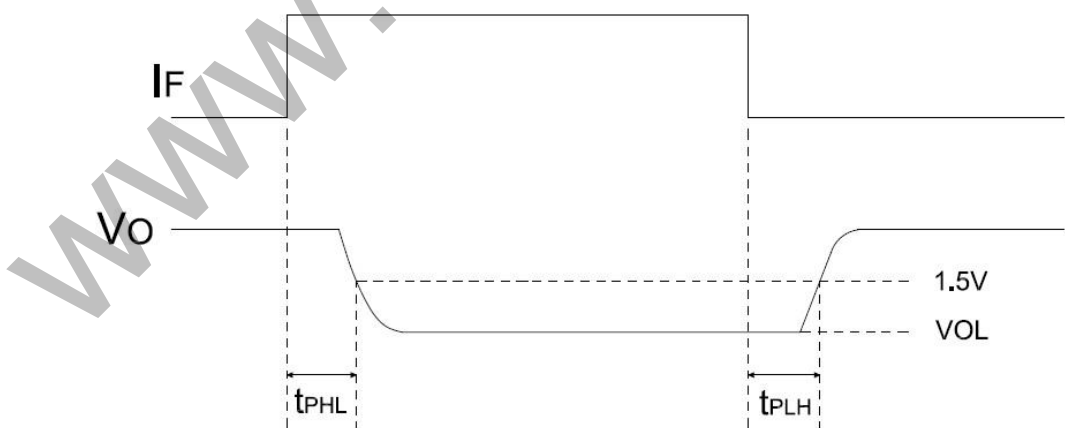
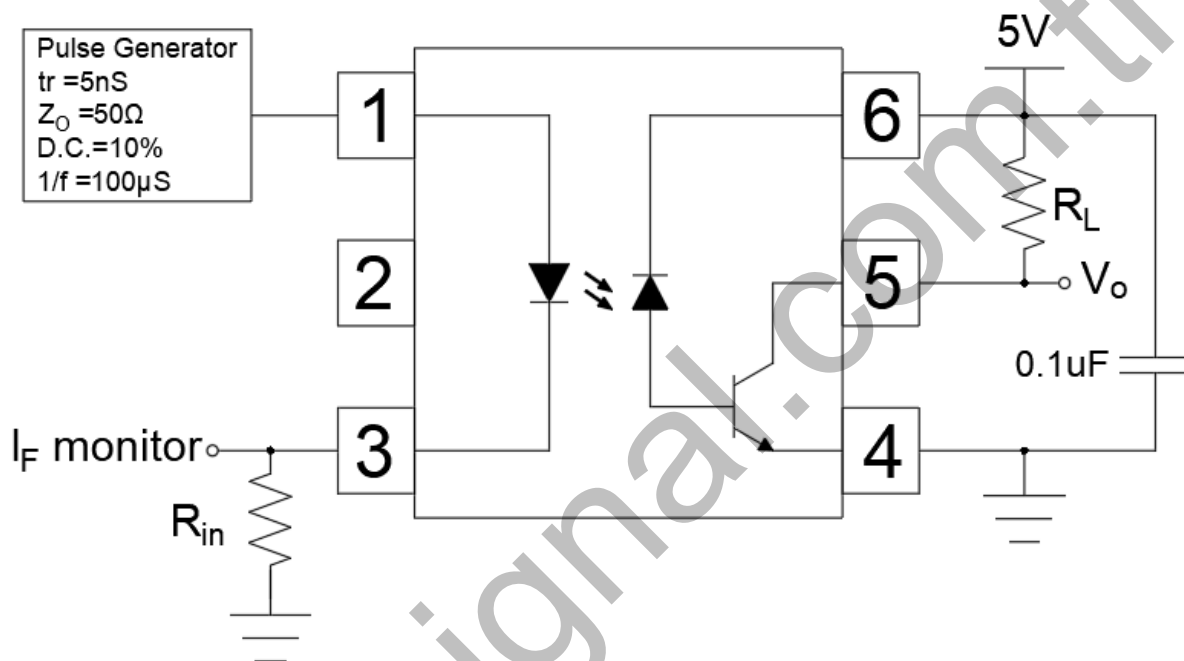


Figure 10



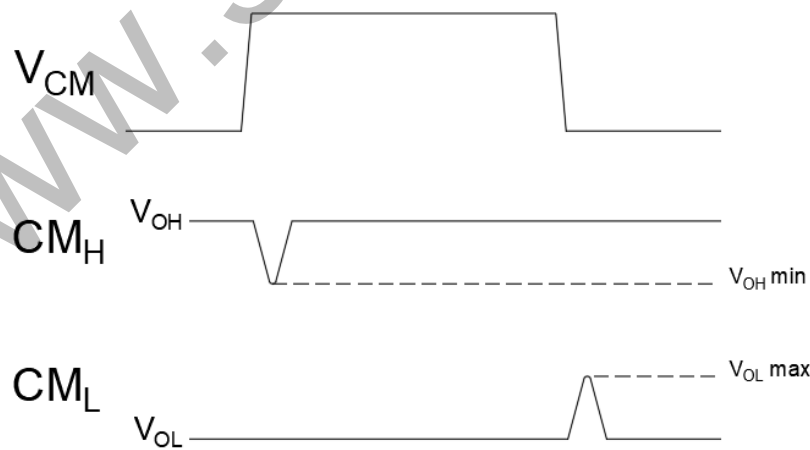
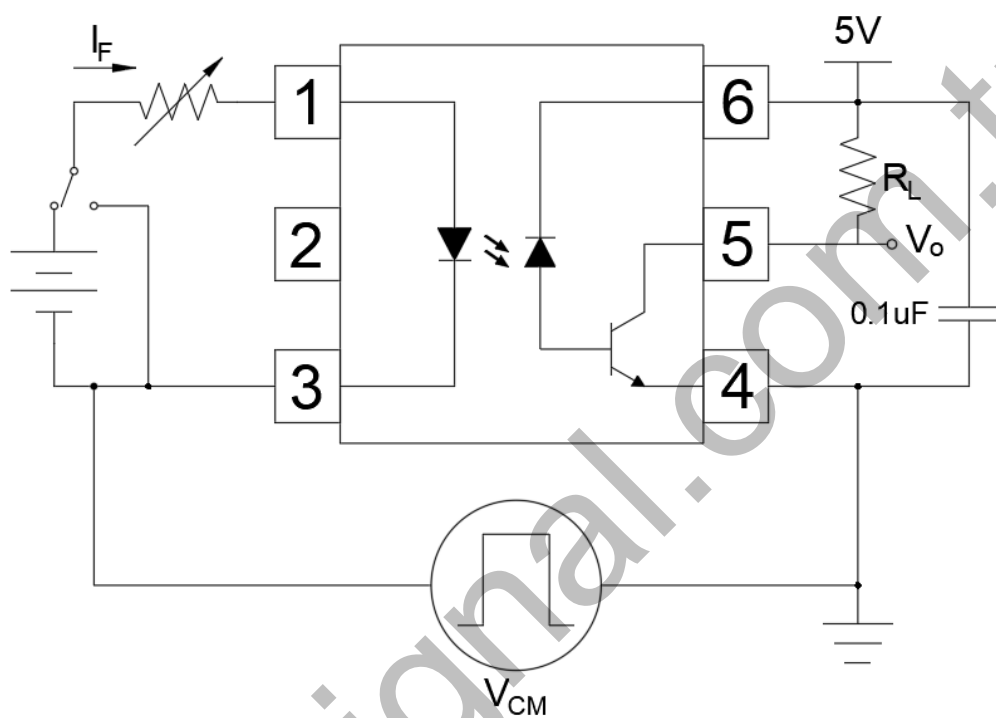
Test Circuits



Switching Time Test Circuit



Test Circuits



CMR Test Circuit

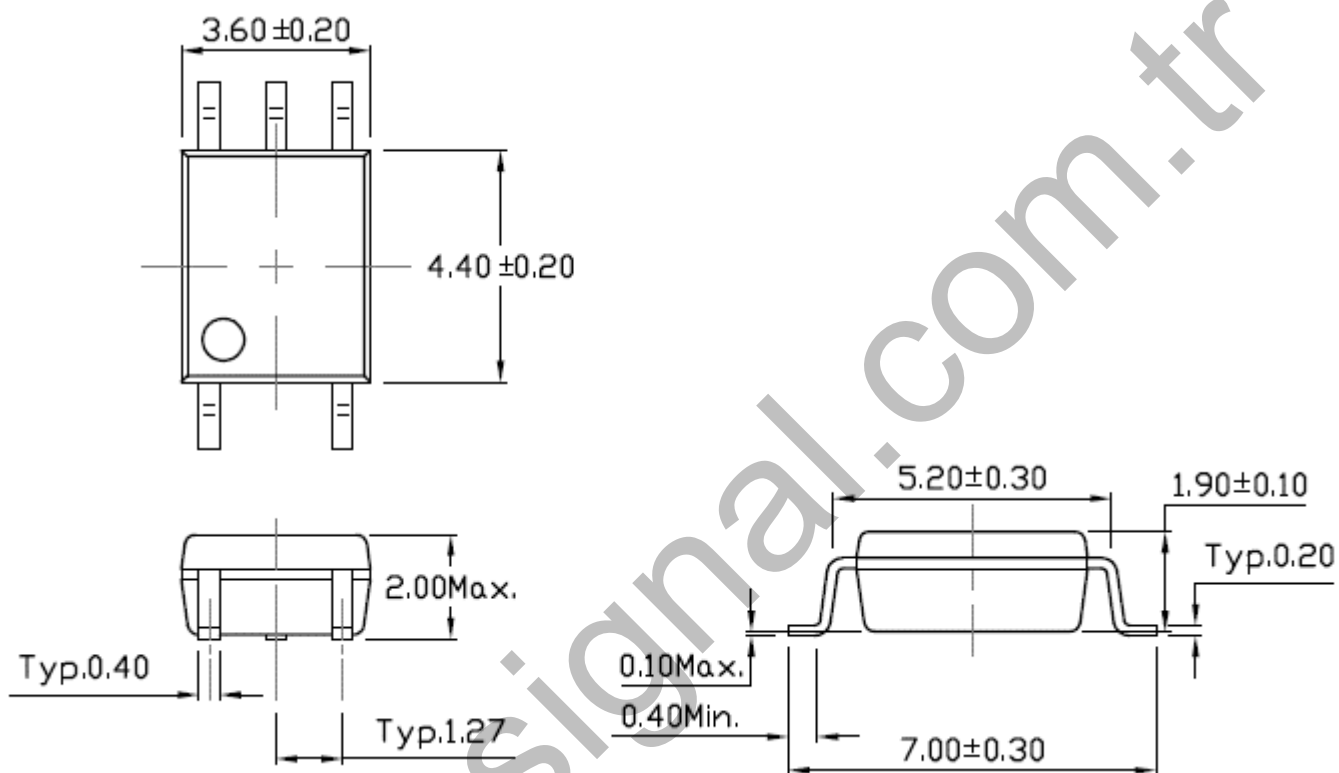


CTM452, CTM453

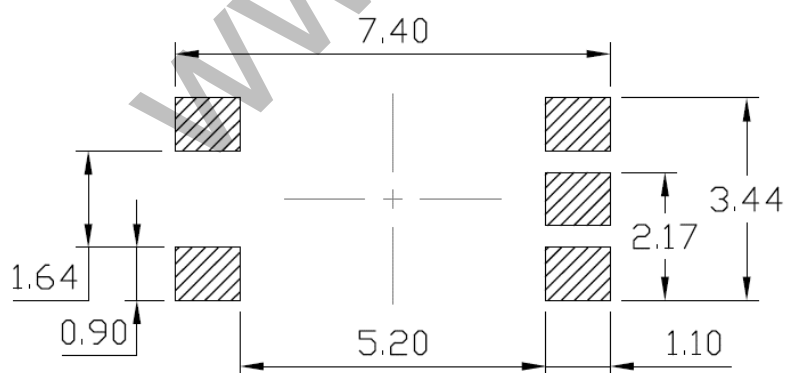
5 Pin Mini-Flat

1 Mbit/s High Speed Transistor Coupler

**Package Dimension** *Dimensions in mm unless otherwise stated*



**Recommended Solder Mask** *Dimensions in mm unless otherwise stated*





## Marking Information



**Note:**

- CT : Denotes “CT Micro”
- M45X : Product Number (X= 2, or 3)
- V : VDE Option
- Y : Fiscal Year
- WW : Work Week
- K : Production Code

## Ordering Information

CTM45X(V)(Z)

X = Part No. (X=2 or 3)

V = VDE Option (V or none)

Z = Tape and reel option (T1, T2, T3, or T4)

<b>Option</b>	<b>Description</b>	<b>Quantity</b>
T1	Surface Mount Lead Forming – With Option 1 Tapping	3000 Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Tapping	3000 Units/Reel
T3	Surface Mount Lead Forming – With Option 3 Tapping	3000 Units/Reel
T4	Surface Mount Lead Forming – With Option 4 Tapping	3000 Units/Reel



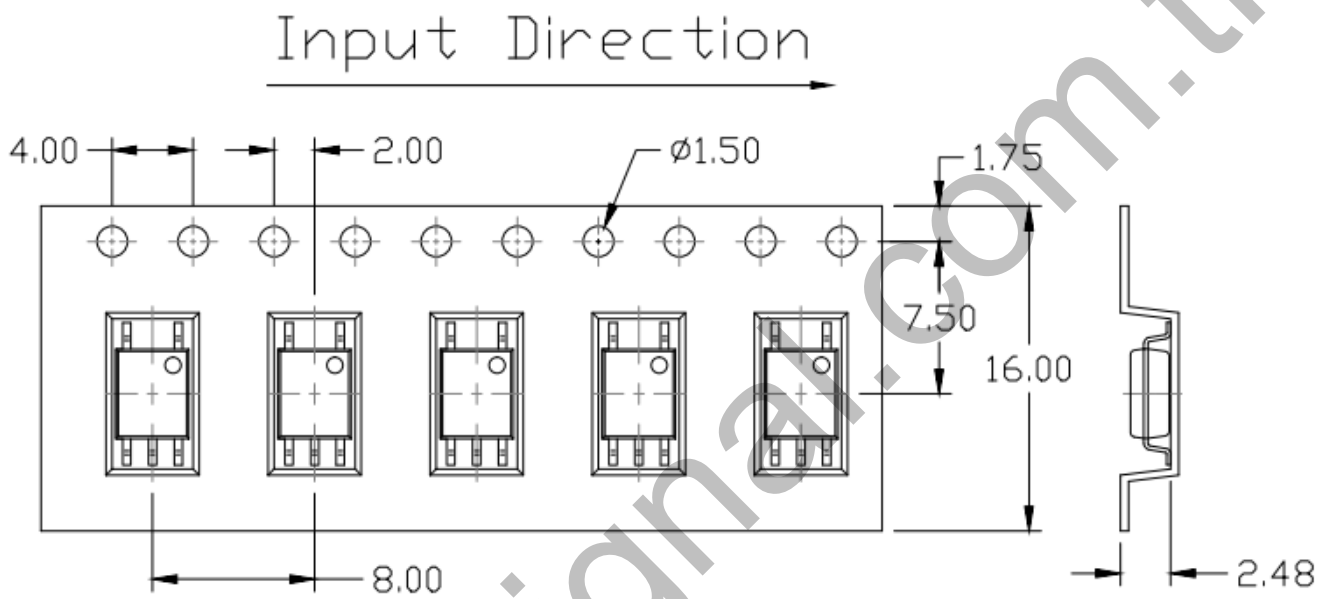
CTM452, CTM453

5 Pin Mini-Flat

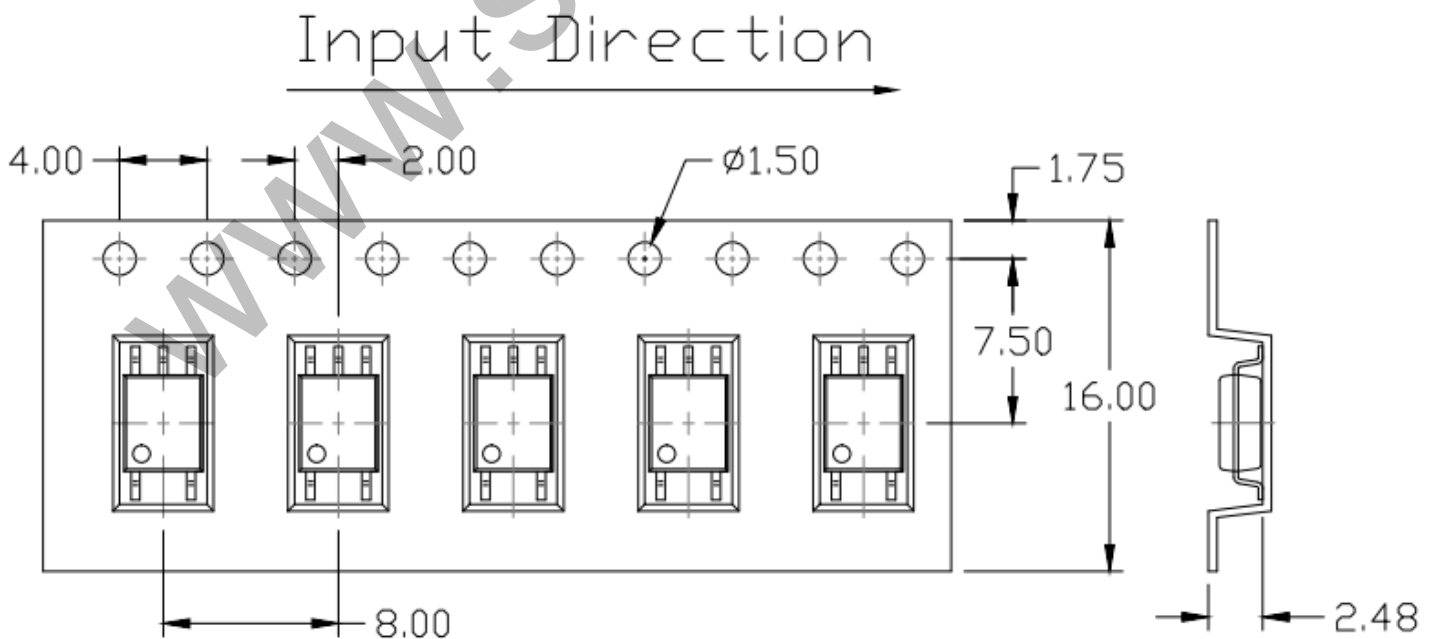
1 Mbit/s High Speed Transistor Coupler

**Carrier Tape Specifications** *Dimensions in mm unless otherwise stated*

**Option T1**



**Option T2**



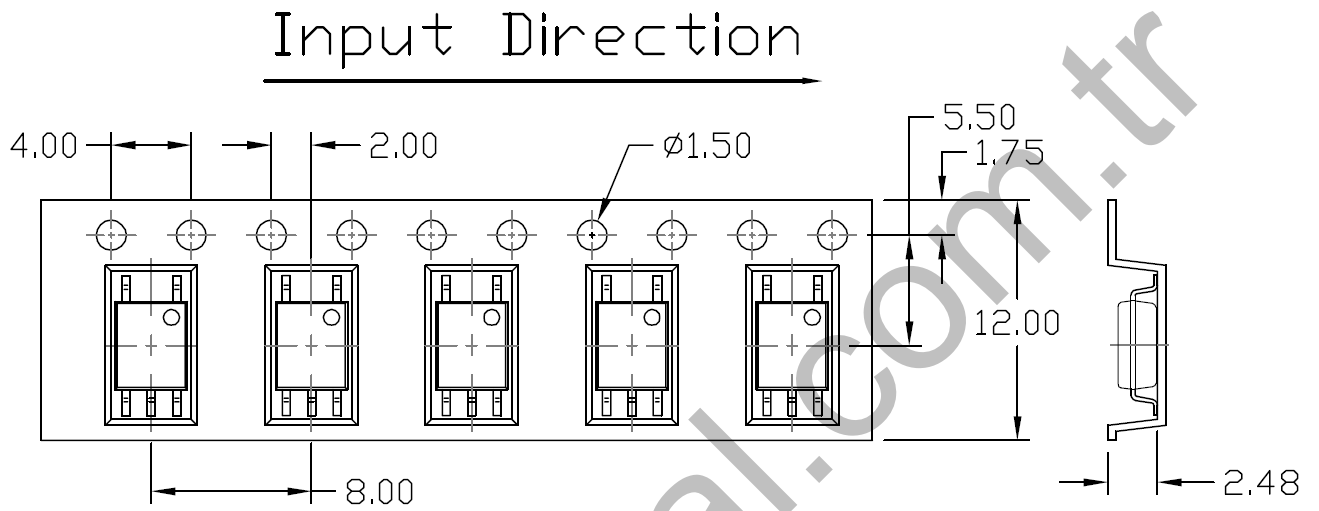


CTM452, CTM453

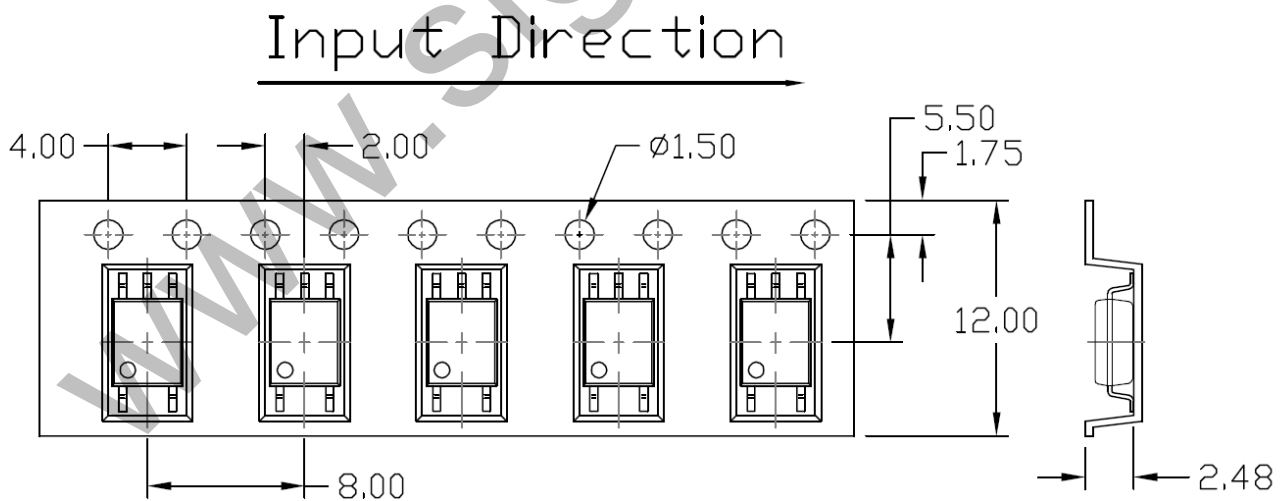
5 Pin Mini-Flat

1 Mbit/s High Speed Transistor Coupler

Option T3

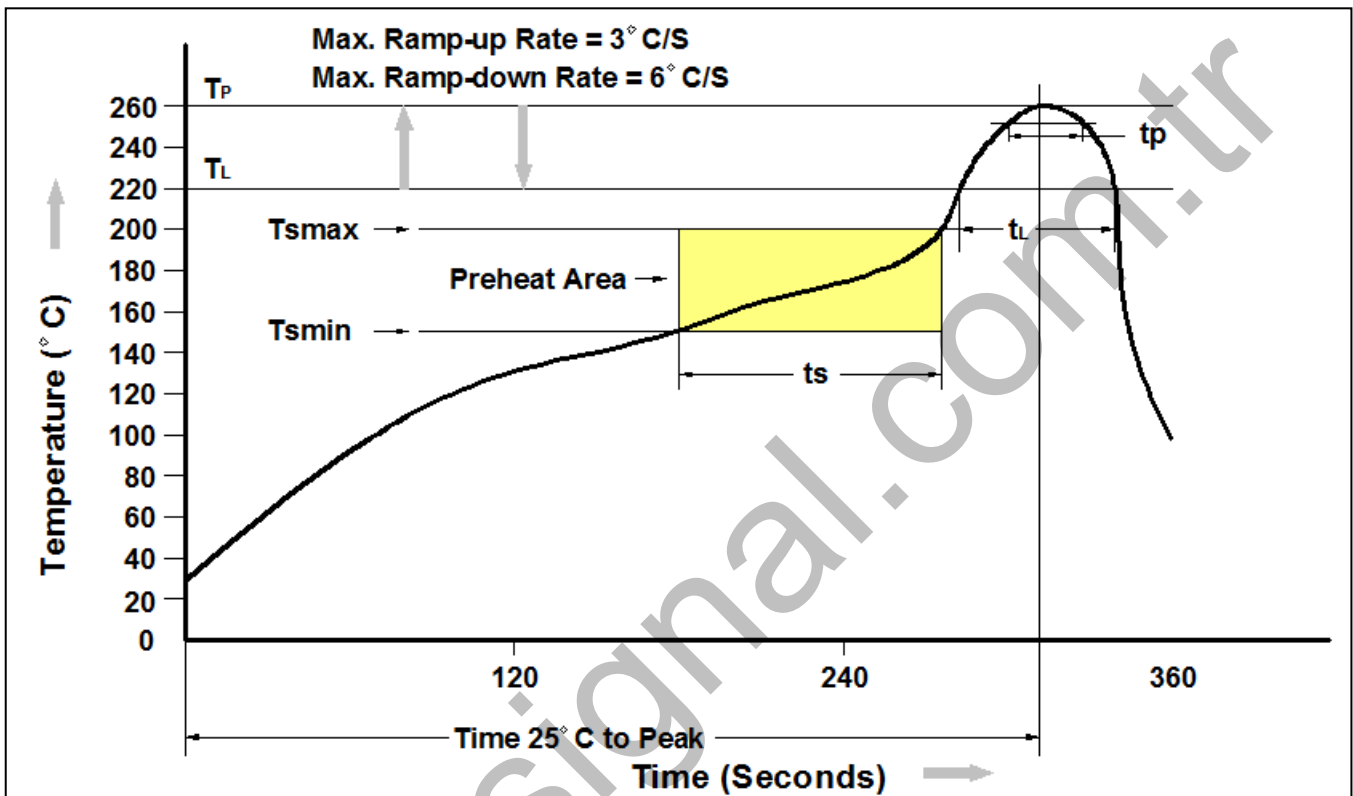


Option T4





**Reflow Profile**



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T <sub>smin</sub> )	150°C
Temperature Max. (T <sub>smax</sub> )	200°C
Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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